

# **DCR590E24**

# **Phase Control Thyristor**

Replaces DS6035-1 DS6035-2 June 2019 (LN38855)

#### **FEATURES**

- Double Side Cooling
- High Surge Capability

### **APPLICATIONS**

- High Power Drives
- High Voltage Power Supplies
- Static Switches

#### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages V <sub>DRM</sub> and V <sub>RRM</sub> V	Conditions
DCR590E24 DCR590E22 DCR590E20	2400 2200 2000	$\begin{split} T_{vj} &= \text{-}40^{\circ}\text{C to 125°C},\\ I_{DRM} &= I_{RRM} = 30\text{mA},\\ V_{DRM}, V_{RRM}t_p &= 10\text{ms},\\ V_{DSM} &\& V_{RSM} =\\ V_{DRM} &\& V_{RRM} + 100V\\ \text{respectively} \end{split}$

Lower voltage grades available.

#### **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

### DCR590E24

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

### **KEY PARAMETERS**

$V_{DRM}$	2400 V
$I_{T(AV)}$	590 A
I <sub>TSM</sub>	7800 A
dV/dt*	1000 V/µs
dI/dt	200 A/μs

### \* Higher dV/dt selections available

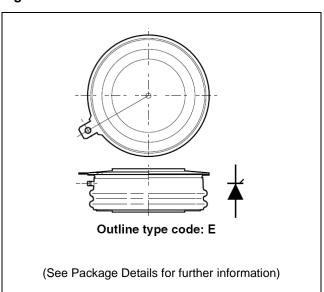


Fig. 1 Package outline

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## **CURRENT RATINGS**

### $T_{\text{case}}$ = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions		Units
Double Si	de Cooled			
I <sub>T(AV)</sub>	Mean on-state current	Half wave resistive load	590	А
I <sub>T(RMS)</sub>	RMS value	-	930	Α
I <sub>T</sub>	Continuous (direct) on-state current	-	830	А

### **SURGE RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125$ °C	7.8	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 0$	0.304	MA <sup>2</sup> s

## THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	DC	-	0.041	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.01	°C/W
T <sub>vj</sub>	Virtual junction temperature	Blocking V <sub>DRM</sub> / <sub>VRRM</sub>		-	125	°C
T <sub>stg</sub>	Storage temperature range			-40	140	°C
Fm	Clamping force			4	6	kN

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# **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Conditions		Min.	Max.	Units
I <sub>RRM</sub> /I <sub>DRM</sub>	Peak reverse and off-state current	At V <sub>RRM</sub> /V <sub>DRM</sub> , T <sub>case</sub> = 125°C		-	30	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V <sub>DRM</sub> , T <sub>j</sub> = 125°C, ga	ate open	1000	-	V/µs
dl/dt	Rate of rise of on-state current	From 67% V <sub>DRM</sub> to 1000A	Repetitive 50Hz	-	200	A/µs
		Gate source 30V, 10Ω,	Non-repetitive	-	1000	A/µs
		$t_r < 0.5 \mu s, T_j = 125 ^{\circ} C$				
V <sub>T</sub>	On-state voltage	IT = 1500A, T <sub>case</sub> = 125°C			2.49	V
$V_{T(TO)}$	Threshold voltage	T <sub>case</sub> = 125°C		-	0.94	V
r <sub>T</sub>	On-state slope resistance	T <sub>case</sub> = 125°C		-	1.036	mΩ
t <sub>gd</sub>	Delay time	$V_D = 67\% V_{DRM}$ , gate source 30V, $10\Omega$		-	3.0	μs
		$t_r = 0.5 \mu s, T_j = 25^{\circ}C$				
ΙL	Latching current	T <sub>j</sub> = 25°C,		-	1	Α
lн	Holding current	T <sub>j</sub> = 25°C,		-	200	mA

## **GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter Test Conditions		Max.	Units
$V_{GT}$	Gate trigger voltage	V <sub>DRM</sub> = 5V, T <sub>case</sub> = 25°C	3	V
$V_{GD}$	Gate non-trigger voltage	At 40% V <sub>DRM</sub> , T <sub>case</sub> = 125°C	0.3	V
I <sub>GT</sub>	Gate trigger current	$V_{DRM} = 5V$ , $T_{case} = 25$ °C	300	mA
I <sub>GD</sub>	Gate non-trigger current	At 40% V <sub>DRM</sub> , T <sub>case</sub> = 125°C	20	mA

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#### **CURVES**

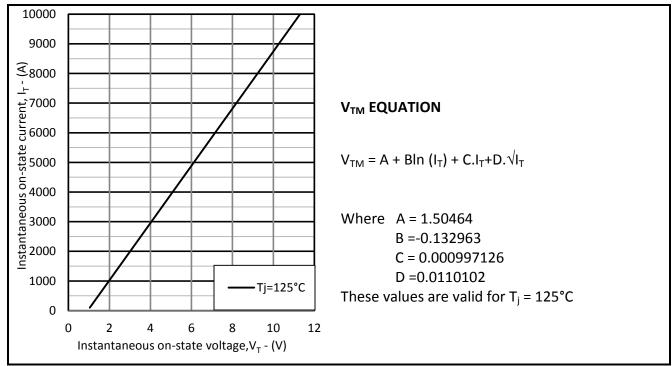


Fig.2 Maximum &minimum on-state characteristics

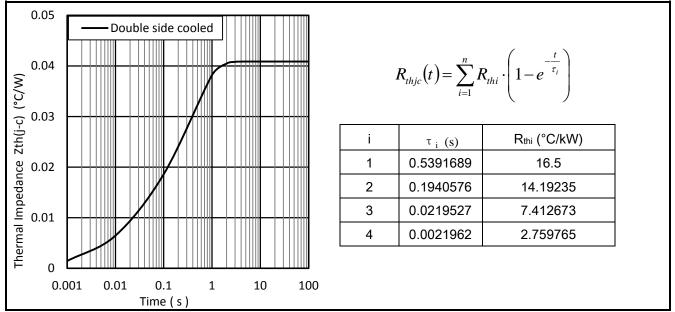
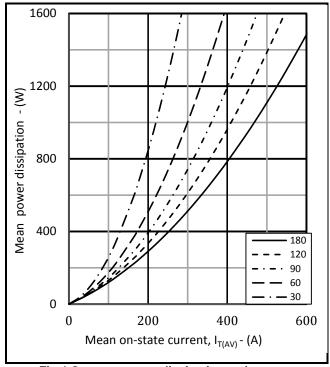
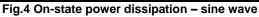


Fig.3 Maximum (limit) transient thermal impedance – junction to case (°C/W)

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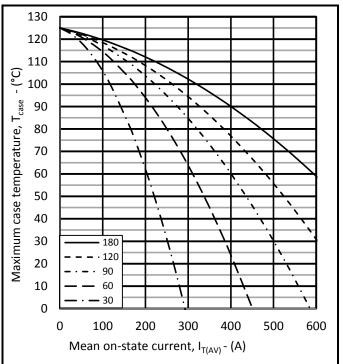


Fig.5 Maximum permissible case temperature, double side cooled – sine wave

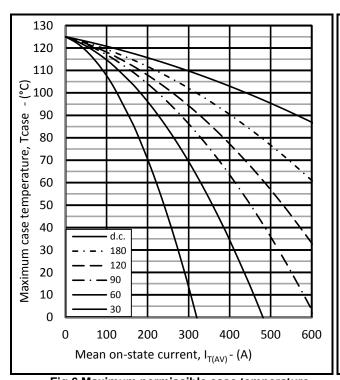


Fig.6 Maximum permissible case temperature, double side cooled – rectangular wave

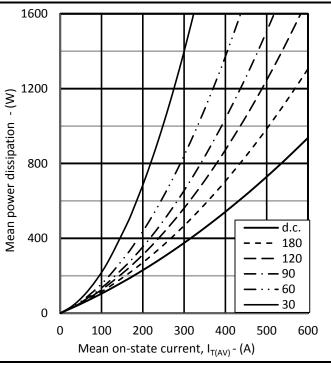
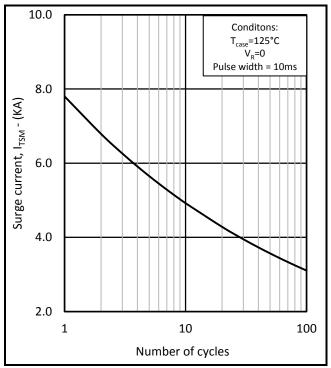


Fig.7 On-state power dissipation – rectangular wave

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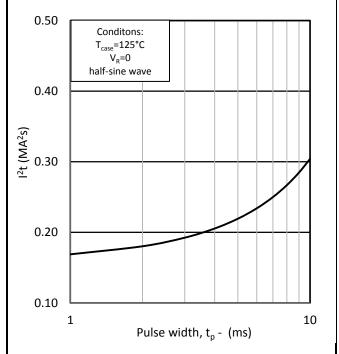


Fig.8 Multi-cycle surge current

Fig.9 Single-cycle I<sup>2</sup>t

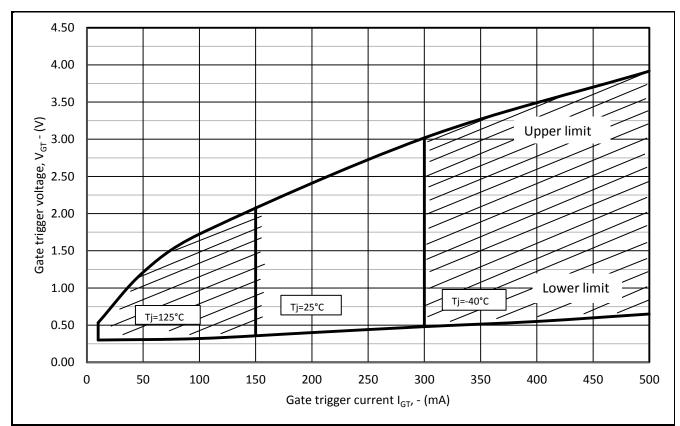


Fig.10 Gate characteristics

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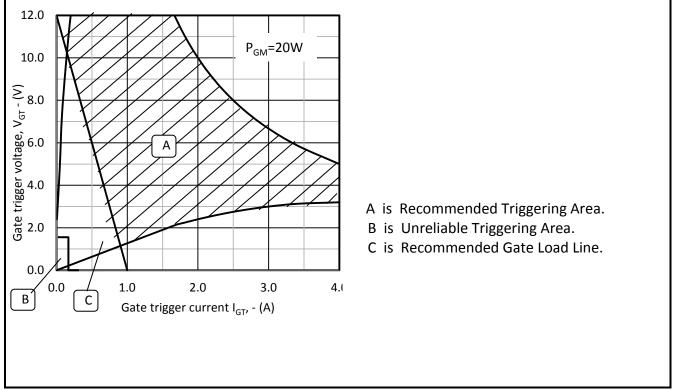


Fig.11 Gate characteristics

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### **PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

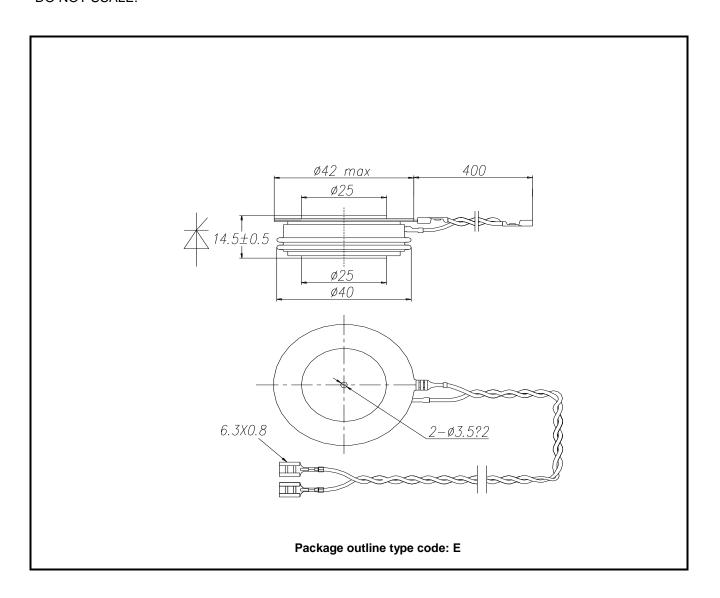


Fig.12 Package outline

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